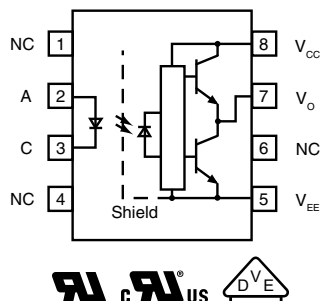
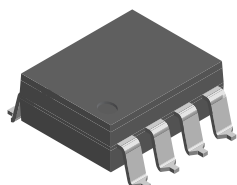


Widebody 2.5 A IGBT and MOSFET Driver



FEATURES

- 2.5 A minimum peak output current
- 10 mm minimum external creepage distance
- 25 kV/ μ s minimum common mode rejection
- $I_{CC} = 2.5$ mA maximum supply current
- Under voltage lock-out (UVLO) with hysteresis
- Wide operating V_{CC} range: 15 V to 32 V
- 0.2 μ s maximum pulse width distortion
- Industrial temperature range: -40 °C to +100 °C
- 0.5 V maximum low level output voltage (V_{OL})
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VOW3120 consists of an infrared light emitting diode optically coupled to an integrated circuit with a power output stage. This optocoupler is ideally suited for driving power IGBTs and MOSFETs used in motor control and inverter applications. The high operating voltage range of the output stage provides the drive voltages required by gate controlled devices. The voltage and current supplied by this optocoupler makes it ideally suited for directly driving IGBTs with ratings up to 1200 V/100 A. For IGBTs with higher ratings, the VOW3120 can be used to drive a discrete power stage which drives the IGBT gate.

The VOW3120 provides higher isolation for applications operating at higher working voltages, and or higher pollution degree criteria. Higher V_{ORM} , V_{OTM} , creepage and clearance distances, make the VOW3120 ideal for many industrial control and power conversion applications.

APPLICATIONS

- Industrial welding equipment
- Motor drives
- Industrial inverters
- Commercial and residential solar inverters
- Wind generator inverters
- EV and plug-in HEV chargers

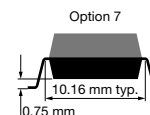
AGENCY APPROVALS

All parts are certified under base model VOW3120. This model number should be used when consulting safety agency documents.

- UL1577
- cUL
- CQC
- DIN EN 60747-5-5 (VDE 0884-5)

ORDERING INFORMATION

V	O	W	3	1	2	0	-	X	0	#	#	T
PART NUMBER								PACKAGE OPTION			TAPE AND REEL	



PACKAGE	UL, cUL, CQC, VDE
SMD-8 widebody, 400 mil, option 7	VOW3120-X017T

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Input forward current		I_F	25	mA
Peak transient input current	< 1 μs pulse width, 300 pps	$I_{F(TRAN)}$	1	A
Reverse input voltage		V_R	5	V
Input power dissipation		P_{diss}	40	mW
LED junction temperature		T_j	125	$^{\circ}\text{C}$
OUTPUT				
High peak output current ⁽¹⁾		$I_{OH(PEAK)}$	2.5	A
Low peak output current ⁽¹⁾		$I_{OL(PEAK)}$	2.5	A
Supply voltage		$(V_{CC} - V_{EE})$	0 to +35	V
Output voltage		$V_{O(PEAK)}$	0 to $+V_{CC}$	V
Output power dissipation		P_{diss}	220	mW
Output junction temperature		T_j	125	$^{\circ}\text{C}$
OPTOCOUPLER				
Isolation test voltage (between emitter and detector)	$t = 1 \text{ min}$	V_{ISO}	5300	V_{RMS}
Storage temperature range		T_{stg}	-55 to +150	$^{\circ}\text{C}$
Ambient operating temperature range		T_{amb}	-40 to +100	$^{\circ}\text{C}$
Total power dissipation		P_{tot}	260	mW
Lead solder temperature ⁽²⁾	For 10 s, 1.6 mm below seating plane	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Maximum pulse width = 10 μs , maximum duty cycle = 0.2 %. This value is intended to allow for component tolerances for designs with I_O peak minimum = 2.5 A. See applications section for additional details on limiting I_{OH} peak.
- ⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

RECOMMENDED OPERATING CONDITION				
PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Power supply voltage	$V_{CC} - V_{EE}$	15	32	V
Input LED current (on)	I_F	10		mA
Input voltage (off)	$V_{F(OFF)}$	-3	0.8	V
Operating temperature	T_{amb}	-40	+100	$^{\circ}\text{C}$

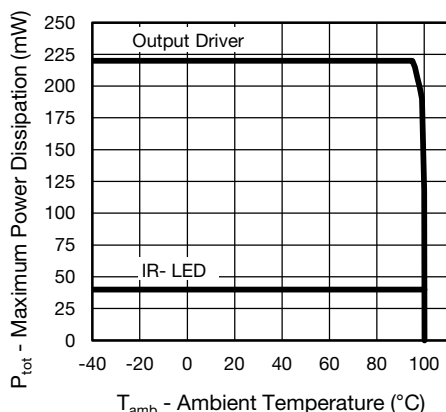
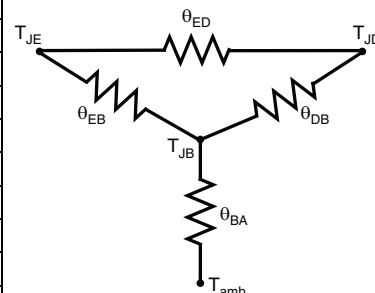


Fig. 1 - Dissipated Operating Power vs. Operating Temperature

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P_{LED}	40	mW
Output power dissipation	P_{OUT}	220	mW
Total power dissipation	P_{TOT}	260	mW
Maximum LED junction temperature	$T_{J \text{ max.}}$	125	°C
Maximum output die junction temperature	$T_{J \text{ max.}}$	125	°C
Thermal resistance, LED to output	θ_{ED}	315	°C/W
Thermal resistance, LED to board	θ_{EB}	300	°C/W
Thermal resistance, output to board	θ_{DB}	80	°C/W
Thermal resistance, board to ambient	θ_{BA}	50	°C/W


Note

- The thermal characteristics table above were measured at 25 °C and the thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note.

ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
High level output current	$V_O = (V_{CC} - 4 \text{ V})$	I_{OH}	0.5			A
	$V_O = (V_{CC} - 15 \text{ V})$	I_{OH}	2.5			A
Low level output current	$V_O = (V_{EE} + 2.5 \text{ V})$	I_{OL}	0.5			A
	$V_O = (V_{EE} + 15 \text{ V})$	I_{OL}	2.5			A
High level output voltage	$I_O = -100 \text{ mA}$	V_{OH}	$V_{CC} - 4$			V
Low level output voltage	$I_O = 100 \text{ mA}$	V_{OL}		0.2	0.5	V
High level supply current	Output open, $I_F = 10 \text{ mA}$ to 16 mA	I_{CCH}			2.5	mA
Low level supply current	Output open, $V_F = -3 \text{ V}$ to $+0.8 \text{ V}$	I_{CCL}			2.5	mA
Threshold input current low to high	$I_O = 0 \text{ mA}$, $V_O > 5 \text{ V}$	I_{FLH}		3.4	8	mA
Threshold input voltage high to low		V_{FHL}	0.8			V
Input forward voltage	$I_F = 10 \text{ mA}$	V_F	1	1.36	1.6	V
Temperature coefficient of forward voltage	$I_F = 10 \text{ mA}$	$\Delta V_F / \Delta T_{amb}$		-1.4		mV/°C
Input reverse breakdown voltage	$I_R = 10 \mu\text{A}$	$V_{(BR)}$	5			V
Input capacitance	$f = 1 \text{ MHz}$, $V_F = 0 \text{ V}$	C_{IN}		45		pF
UVLO threshold	$V_O \geq 5 \text{ V}$, $I_F = 10 \text{ mA}$	V_{UVLO+}	11		13.5	V
		V_{UVLO-}	9.5		12	V
UVLO hysteresis		$UVLO_{HYS}$		1.6		V
Capacitance (Input to Output)	$f = 1 \text{ MHz}$, $V_F = 0 \text{ V}$	C_{IO}		0.9		pF

Note

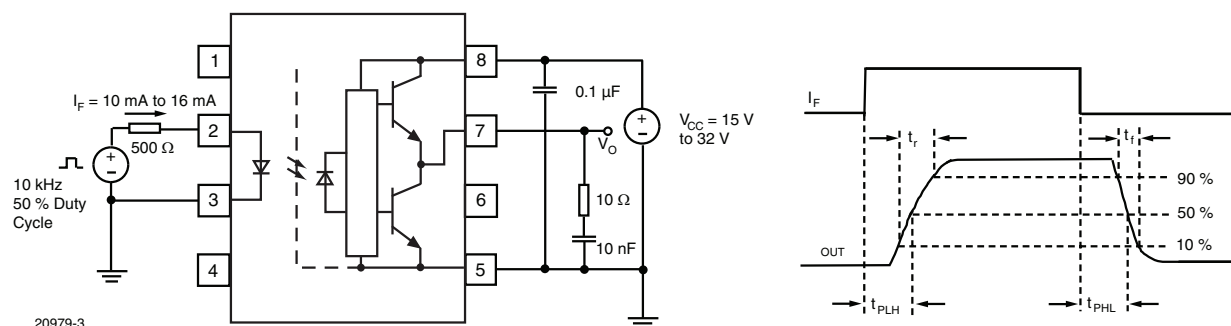
- Minimum and maximum values were tested over recommended operating conditions ($T_{amb} = -40 \text{ °C}$ to $+100 \text{ °C}$, $I_{F(ON)} = 10 \text{ mA}$ to 16 mA , $V_{F(OFF)} = -3 \text{ V}$ to 0.8 V , $V_{CC} = 15 \text{ V}$ to 32 V , $V_{EE} = \text{ground}$) unless otherwise specified. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements. All typical values were measured at $T_{amb} = 25 \text{ °C}$ and with $V_{CC} - V_{EE} = 32 \text{ V}$.

SWITCHING CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay time to logic low output	$R_g = 10\ \Omega$, $C_g = 10\ \text{nF}$, $f = 10\ \text{kHz}$, duty cycle = 50 %	t_{PLH}	0.1	0.25	0.5	μs
Propagation delay time to logic high output	$R_g = 10\ \Omega$, $C_g = 10\ \text{nF}$, $f = 10\ \text{kHz}$, duty cycle = 50 %	t_{PLH}	0.1	0.25	0.5	μs
Pulse width distortion	$R_g = 10\ \Omega$, $C_g = 10\ \text{nF}$, $f = 10\ \text{kHz}$, duty cycle = 50 %	PWD			0.3	μs
Rise time	$R_g = 10\ \Omega$, $C_g = 10\ \text{nF}$, $f = 10\ \text{kHz}$, duty cycle = 50 %	t_r		0.1		μs
Fall time	$R_g = 10\ \Omega$, $C_g = 10\ \text{nF}$, $f = 10\ \text{kHz}$, duty cycle = 50 %	t_f		0.1		μs
UVLO turn on delay	$V_O > 5\ \text{V}$, $I_F = 10\ \text{mA}$	$T_{\text{UVLO-ON}}$		0.8		μs
UVLO turn off delay	$V_O < 5\ \text{V}$, $I_F = 10\ \text{mA}$	$T_{\text{UVLO-OFF}}$		0.6		μs

Note

- Minimum and maximum values were tested over recommended operating conditions ($T_{\text{amb}} = -40\ ^\circ\text{C}$ to $+100\ ^\circ\text{C}$, $I_{\text{F(ON)}} = 10\ \text{mA}$ to $16\ \text{mA}$, $V_{\text{F(OFF)}} = -3\ \text{V}$ to $0.8\ \text{V}$, $V_{\text{CC}} = 15\ \text{V}$ to $32\ \text{V}$, $V_{\text{EE}} = \text{ground}$) unless otherwise specified. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements. All typical values were measured at $T_{\text{amb}} = 25\ ^\circ\text{C}$ and with $V_{\text{CC}} - V_{\text{EE}} = 32\ \text{V}$.


Fig. 2 - t_{PLH} , t_{PHL} , t_r and t_f Test Circuit and Waveforms

COMMON MODE TRANSIENT IMMUNITY

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode transient immunity at logic high output	$T_{\text{amb}} = 25\ ^\circ\text{C}$, $I_F = 10\ \text{mA}$ to $16\ \text{mA}$, $V_{\text{CM}} = 1500\ \text{V}$, $V_{\text{CC}} = 32\ \text{V}$	$ CM_H $	25	50		$\text{kV}/\mu\text{s}$
Common mode transient immunity at logic low output	$T_{\text{amb}} = 25\ ^\circ\text{C}$, $V_{\text{CM}} = 1500\ \text{V}$, $V_{\text{CC}} = 32\ \text{V}$, $V_F = 0\ \text{V}$	$ CM_L $	25	45		$\text{kV}/\mu\text{s}$

Note

- Minimum and maximum values were tested over recommended operating conditions ($T_{\text{amb}} = -40\ ^\circ\text{C}$ to $+100\ ^\circ\text{C}$, $I_{\text{F(ON)}} = 10\ \text{mA}$ to $16\ \text{mA}$, $V_{\text{F(OFF)}} = -3\ \text{V}$ to $0.8\ \text{V}$, $V_{\text{CC}} = 15\ \text{V}$ to $32\ \text{V}$, $V_{\text{EE}} = \text{ground}$) unless otherwise specified. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements. All typical values were measured at $T_{\text{amb}} = 25\ ^\circ\text{C}$ and with $V_{\text{CC}} - V_{\text{EE}} = 32\ \text{V}$.

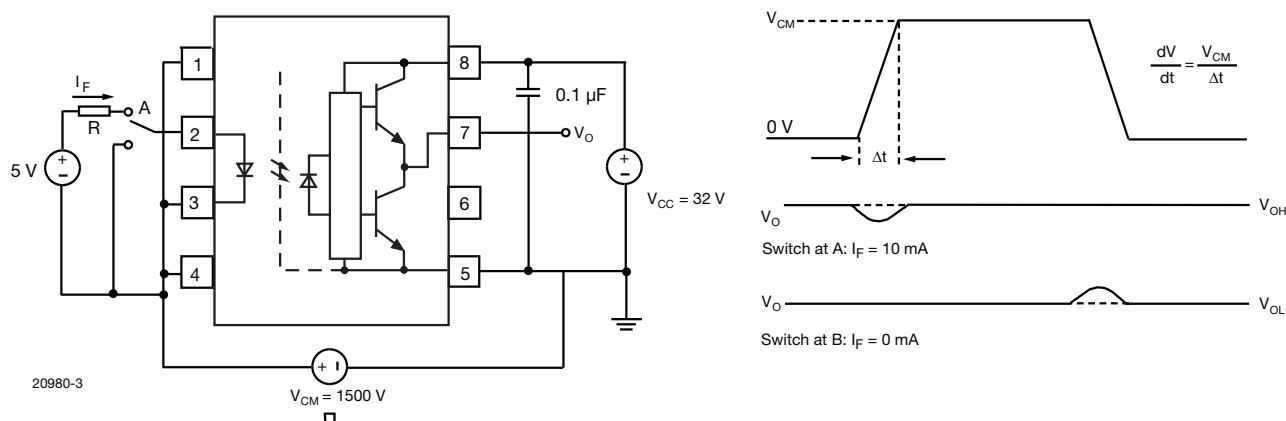


Fig. 3 - CMR Test Circuit and Waveforms

SAFETY AND INSULATION RATINGS				
PARAMETER		SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS				
Output safety power		P_{SO}	800	mW
Input safety current		I_{SI}	350	mA
Safety temperature		T_S	175	°C
Comparative tracking index		CTI	250	
INSULATION RATED PARAMETERS				
Maximum withstanding isolation voltage	$t = 1 \text{ min}$	V_{ISO}	5300	V_{RMS}
Maximum transient isolation voltage		V_{IOTM}	8000	V_{peak}
Maximum repetitive isolation voltage		V_{IORM}	1414	V_{peak}
Insulation resistance	$T_{amb} = 25 \text{ °C}, V_{DC} = 500 \text{ V}$	R_{IO}	$\geq 10^{12}$	Ω
Isolation resistance	$T_{amb} = 100 \text{ °C}, V_{DC} = 500 \text{ V}$	R_{IO}	$\geq 10^{11}$	Ω
Input to output test voltage, method b	$V_{IORM} \times 1.875 = V_{PR}$, 100 % production test with $t_M = 1 \text{ s}$, partial discharge $< 5 \text{ pC}$	V_{PR}	2651	V_{peak}
Input to output test voltage, method a	$V_{IORM} \times 1.6 = V_{PR}$, 100 % production test with $t_M = 10 \text{ s}$, partial discharge $< 5 \text{ pC}$	V_{PR}	2262	V_{peak}
Climatic classification (according to IEC 68 part 1)			40/110/21	
Environment (pollution degree in accordance to DIN VDE 0109)			2	
Clearance distance (DIP-8 widebody)			≥ 10	mm
Creepage distance (DIP-8 widebody)			≥ 10	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

- As per IEC 60747-5-5, §7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

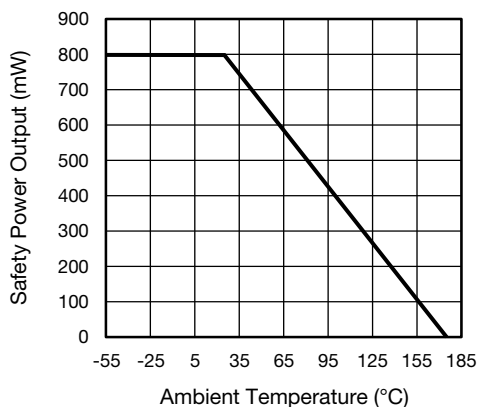


Fig. 4 - Safety Power Dissipation vs. Ambient Temperature

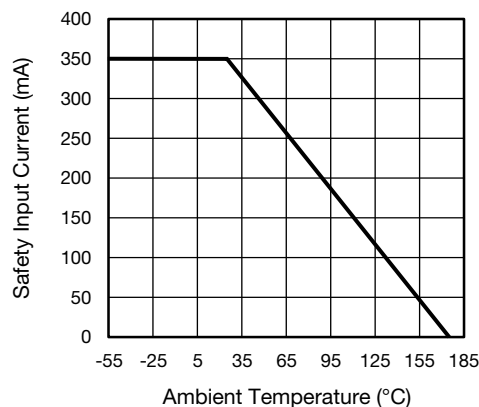


Fig. 5 - Safety Input Current vs. Ambient Temperature

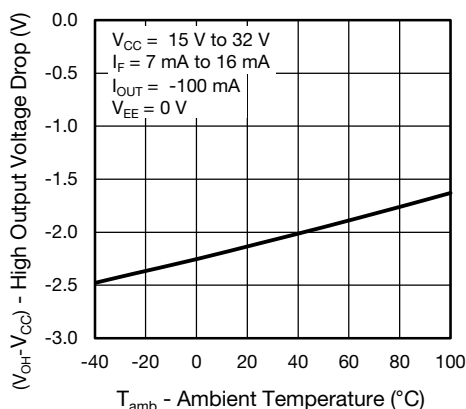
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 6 - High Output Voltage Drop vs. Ambient Temperature

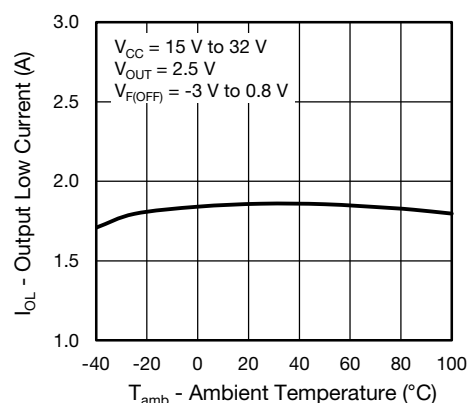


Fig. 9 - Output Low Current vs. Ambient Temperature

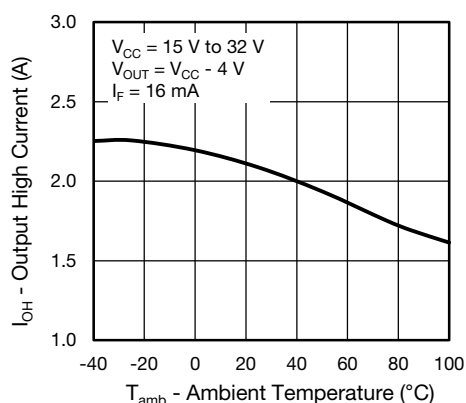


Fig. 7 - Output High Current vs. Ambient Temperature

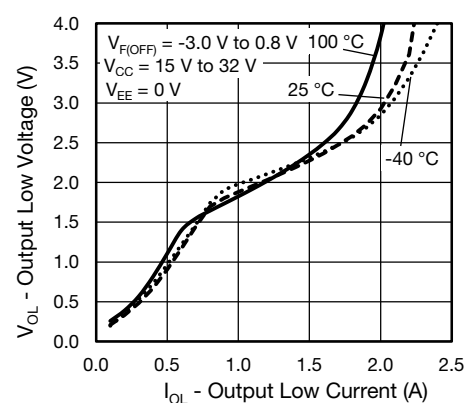


Fig. 10 - Output Low Voltage vs. Output Low Current

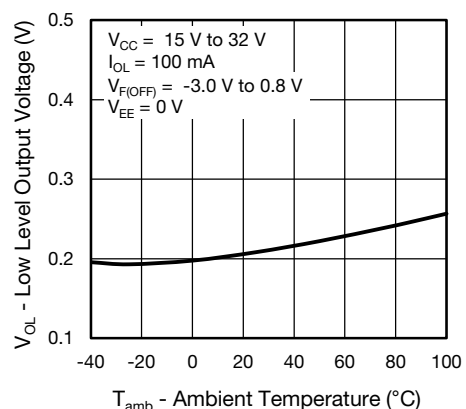


Fig. 8 - Low Level Output Voltage vs. Ambient Temperature

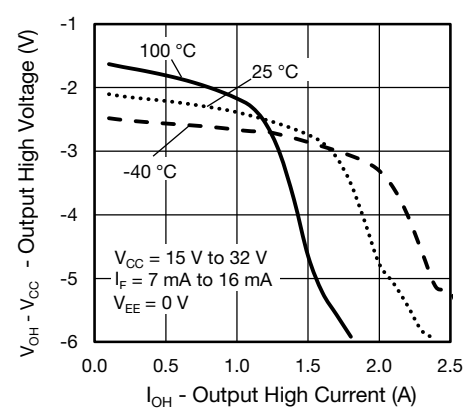


Fig. 11 - Output High Voltage vs. Output High Current

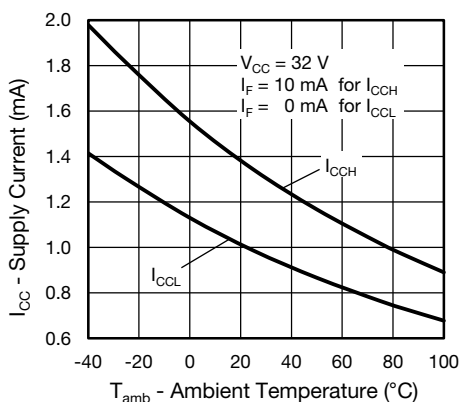


Fig. 12 - Supply Current vs. Ambient Temperature

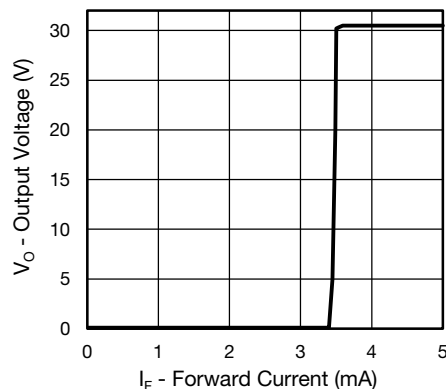


Fig. 15 - Output Voltage vs. Forward Current

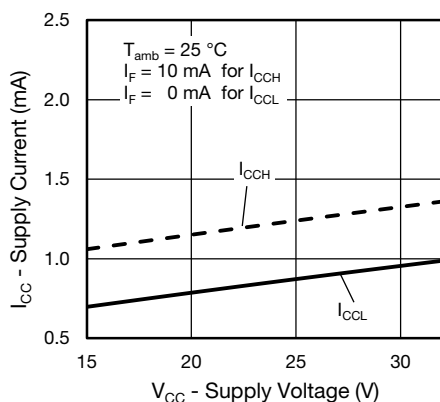


Fig. 13 - Supply Current vs. Supply Voltage

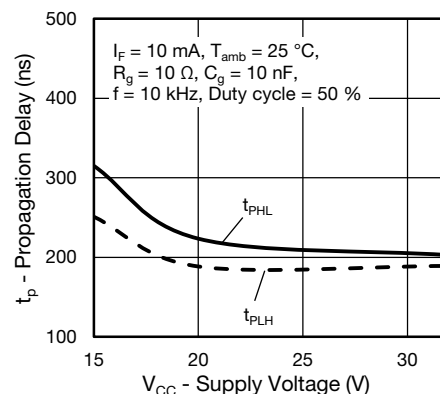


Fig. 16 - Propagation Delay vs. Supply Voltage

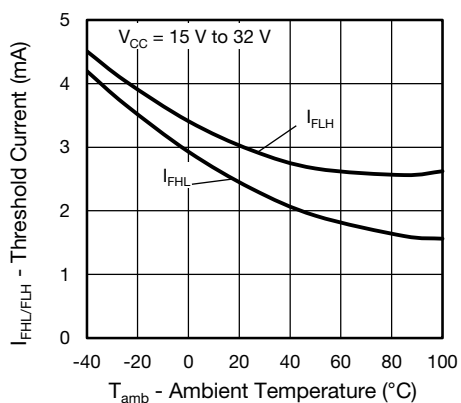


Fig. 14 - threshold Current vs. Ambient Temperature

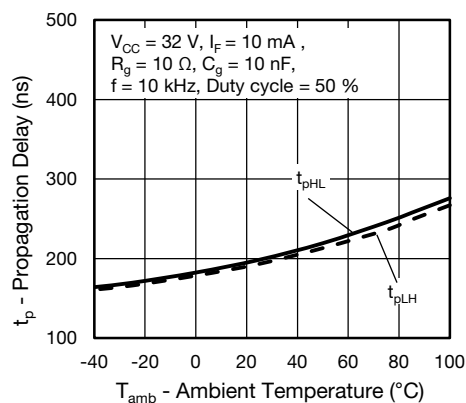


Fig. 17 - Propagation Delay vs. Ambient Temperature

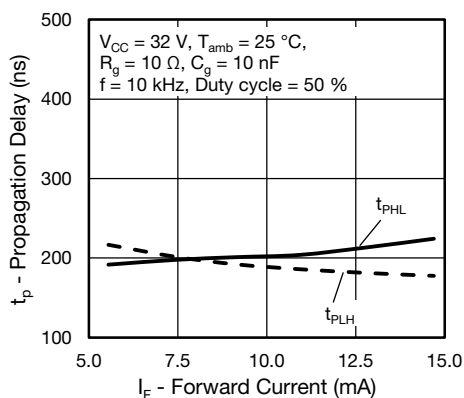


Fig. 18 - Propagation Delay vs. Forward Current

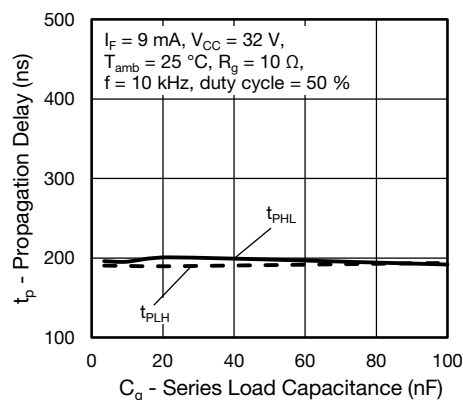


Fig. 20 - Propagation Delay vs. Series Load Capacitance

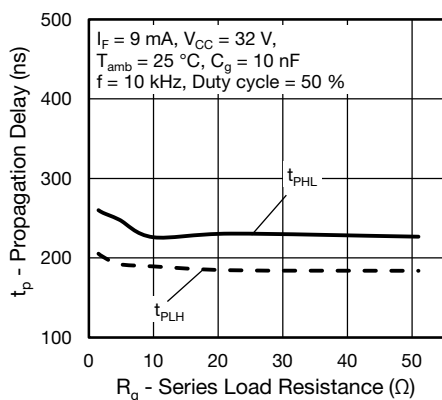


Fig. 19 - Propagation Delay vs. Series Load Resistance

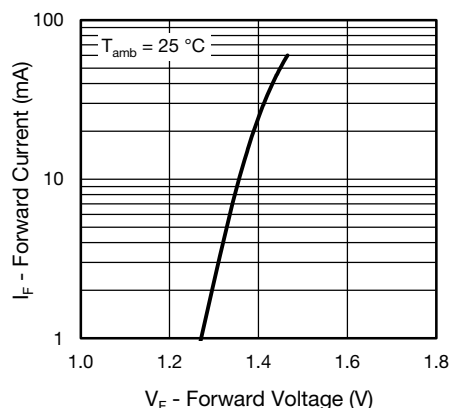
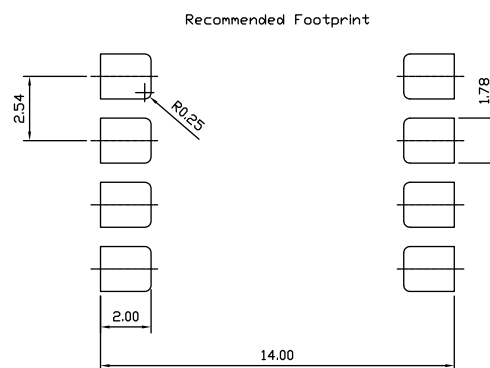
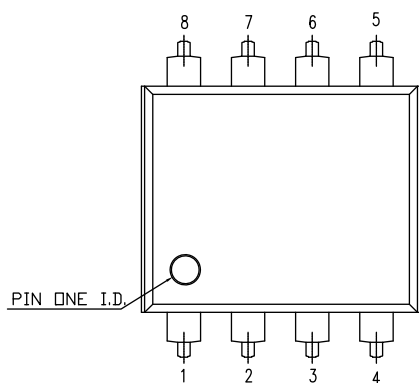
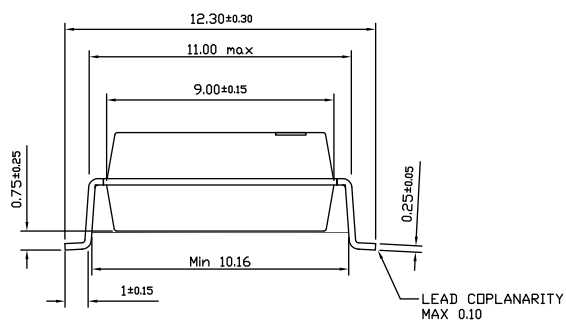
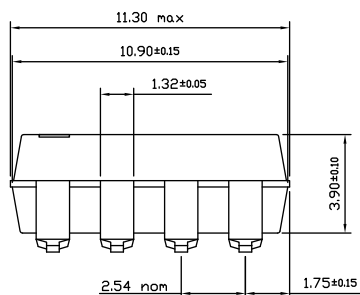
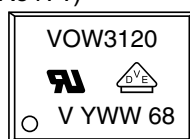


Fig. 21 - Forward Current vs. Forward Voltage

PACKAGE DIMENSIONS in millimeters

SMD-8, widebody (Option 7)

PACKAGE MARKING (Example of VOW3120-X017T)

Notes

- The VDE logo is only marked on option 1 parts.
- Tape and reel (T) and package option (option 7) are not part of the package markings.

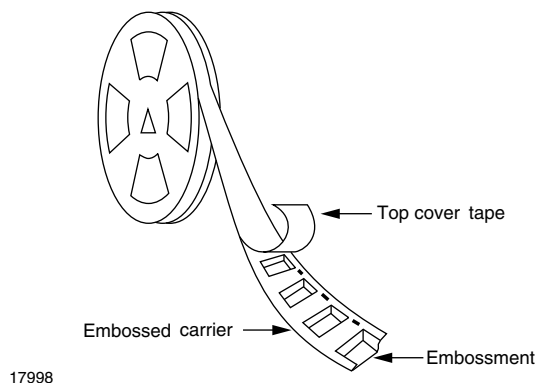
PACKING INFORMATION (Tape and Reel)


Fig. 22 - Tape and Reel Shipping Medium

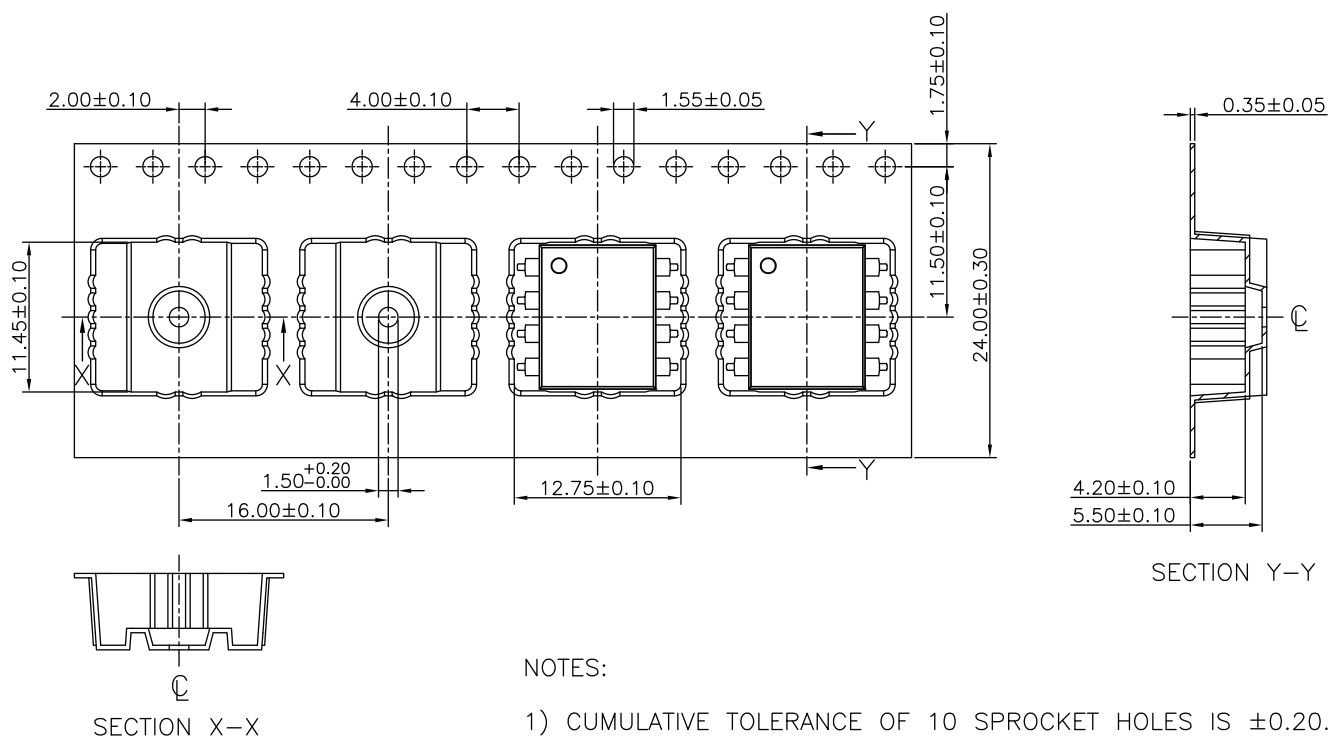


Fig. 23 - Tape and Reel Packing Option 7 (750 parts per reel)



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.